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1. General description

The NX5P1000 is an advanced power switch and ESD- protection device for USB OTG applications. The device includes under voltage and over voltage lockout, over-current, over-temperature, reverse bias and in-rush current protection circuits. These circuits are designed to isolate a VBUS OTG voltage source automatically from a VBUS interface pin when a fault condition occurs. The device features two power switch terminals, one input (VINT) and one output (VBUS). It has a current limit input (ILIM) for defining the over-current and in-rush current limit. A voltage detect output (VDET) is used to determine when VINT is in the correct voltage range. An open-drain fault output (FAULT) indicates when a fault condition has occurred and an enable input (EN) controls the state of the switch. When EN is set LOW the device enters a low-power mode, disabling all protection circuits except the undervoltage lockout. The low-power mode can be entered at anytime unless the over temperature protection circuit has been triggered.

Designed for operation from 3 V to 5.5 V, it is used in power domain isolation applications to protect from out of range operation. The enable input includes integrated logic level translation making the device compatible with lower voltage processors and controllers.

2. Features and benefits

- Wide supply voltage range from 3 V to 5.5 V
- 30 V tolerant on VBUS
- I_{SW} maximum 1 A continuous current
- Very low ON resistance: 100 mΩ (maximum) at a supply voltage of 4.0 V
- Low-power mode (ground current 20 μA typical)
- 1.8 V control logic
- Soft start turn-on slew rate
- Protection circuitry
 - Over-temperature protection
 - Over-current protection with low current output mode
 - Reverse bias current/Back drive protection
 - Overvoltage lockout
 - Undervoltage lockout
 - Analog voltage limited VBUS monitor path
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
 - IEC61000-4-2 contact discharge exceeds 8 kV for pins VBUS, D-, D+ and ID
- Specified from –40 °C to +85 °C



3. Applications

USB OTG applications

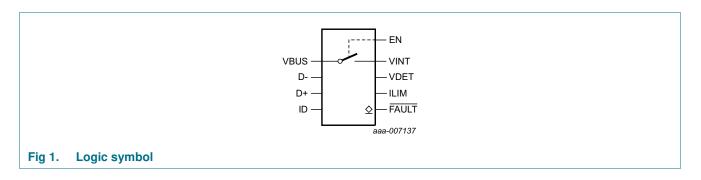
4. Ordering information

| Table 1. Ordering information | | | | | | | | |
|---------------------------------------|-------------------|---------|---|----------|--|--|--|--|
| Type number | Package | | | | | | | |
| | Temperature range | Name | Description | Version | | | | |
| NX5P1000UK | –40 °C to +85 °C | WLCSP12 | wafer level chip-scale package; 12 bumps; 1.36 \times 1.66 \times 0.51 mm, 0.4 mm pitch (Backside Coating included) | NX5P1000 | | | | |

5. Marking

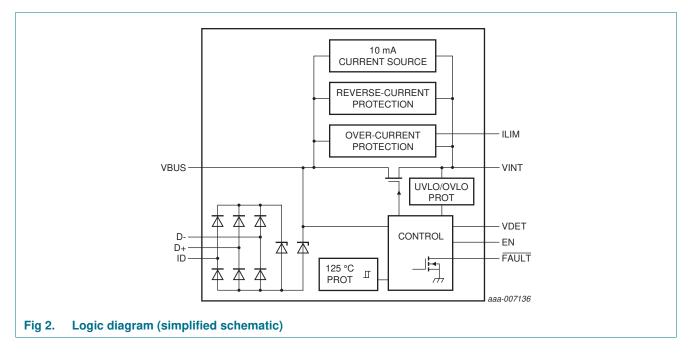
| Table 2. Marking codes | |
|--------------------------|--------------|
| Type number | Marking code |
| NX5P1000UK | NX5P1 |

6. Functional diagram



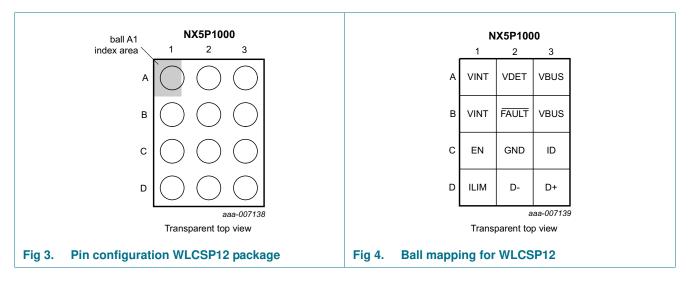
NX5P1000

Logic controlled high-side power switch



7. Pinning information

7.1 Pinning



7.2 Pin description

| Table 3. | Pin description | | |
|----------|-----------------|--------|------------------------------|
| Symbol | | Pin | Description |
| VINT | | A1, B1 | internal circuitry voltage I |
| VBUS | | A3, B3 | external connector voltage O |
| EN | | C1 | enable input (active HIGH) I |
| ILIM | | D1 | current limiter I/O |

NX5P1000

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Logic controlled high-side power switch

| Table 3. | Pin description continued | |
|----------|---------------------------|--|
| Symbol | Pin | Description |
| VDET | A2 | VBUS voltage level indicator O |
| FAULT | B2 | fault condition indicator (open-drain; active LOW) |
| GND | C2 | ground (0 V) |
| D- | D2 | ESD-protection I/O |
| D+ | D3 | ESD-protection I/O |
| ID | C3 | ESD-protection I/O |

8. Functional description

| EN | VINT | VBUS | FAULT | Operation mode |
|----|----------------|---|-------|---|
| Х | 0 V | Z | L | no supply |
| Х | 0 V | < 30 V | Z | disabled; switch open |
| Х | < 3.2 V | Z | L | undervoltage lockout; switch open |
| Н | > 5.5 V | Z | L | overvoltage lockout; switch open |
| Н | 3.2 V to 5.5 V | Z | L | over-temperature; switch open |
| L | 3.2 V to 5.5 V | Z | Z | disabled; switch open |
| Н | 3.2 V to 5.5 V | VBUS = VINT | Z | enabled; switch closed; active |
| Н | 3.2 V to 5.5 V | 0 V to VINT | L | over-current; switch open; constant current on VBUS |
| Η | 3.2 V to 5.5 V | 0 V to VINT | L | when ILIM is connected to GND, VBUS is supplied with 10 mA current source |
| Η | 3.2 V to 5.5 V | VINT + 30 mV < VBUS < VINT + 0.45 V (> 4 ms) | L | reverse bias current/back drive; switch open |
| Н | 3.2 V to 5.5 V | VBUS > VINT + 0.45 V | L | reverse bias current/back drive; switch open |

[1] H = HIGH voltage level; L = LOW voltage level, Z = high-impedance OFF-state, X = Don't care.

Table 5. Function table VDET versus VBUS^[1]

| VBUS | VDET | Operation mode |
|-------------------|--------------------|---------------------------|
| 3 V < VBUS < 30 V | 1.5 < VDET < 5.5 V | VDET detects VBUS voltage |

[1] See Figure 22.

8.1 EN input

When the EN is set LOW, the N-channel MOSFET is disabled. The device enters low-power mode disabling all protection circuits except the undervoltage lockout circuit and setting the FAULT output high impedance. When EN is set HIGH, all protection circuits are enabled. If an R_{ILIM} current limit resistor is detected and no fault conditions exist, the N-channel MOSFET is enabled.

8.2 Undervoltage lockout

A

Independent of the logic level on the EN pin, the undervoltage lockout (UVLO) circuit disables the N-channel MOSFET. It sets the FAULT output LOW and enters low-power mode until VINT > 3.2 V. Once VINT > 3.2 V, the state of the N-channel MOSFET controls the EN pin. The UVLO circuit remains active in low-power mode.

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8.3 Overvoltage lockout

When EN is set HIGH, the overvoltage lockout (OVLO) circuit disables the N-channel MOSFET. If VINT > 5.75 V, the FAULT output is set LOW. The OVLO circuit is disabled in low-power mode and does not influence the FAULT output state. If the OVLO circuit is active, setting the EN pin LOW returns the device to low-power mode.

8.4 ILIM

The over-current protection circuit's (OCP) trigger value I_{ocp} , can be set using an external resistor R_{ILIM} connected to the ILIM pin (see Figure 6). When EN is set HIGH and the ILIM pin is grounded, the N-channel MOSFET is disabled. In addition, VBUS is supplied by the 10 mA current source and the FAULT output set LOW.

8.5 Over-current protection

If the current through the N-channel MOSFET exceeds I_{ocp} for 20 µs or VBUS < VINT – 200 mV, the over-current protection (OCP) circuit disables the N-channel MOSFET within 2 µs. It supplies VBUS from the 10 mA current source and indicates a fault condition by setting the FAULT pin LOW. The OCP circuit is automatically reset when VINT > VBUS > VINT – 200 mV for 20 µs. The N-channel MOSFET assumes the state defined by the EN input, the 10 mA current source is disconnected and the FAULT pin is set high impedance. If the OCP circuit is active, setting the EN pin LOW returns the device to low-power mode.

8.6 Over-temperature protection

When EN is set HIGH and the device temperature exceeds 125 °C, the Over-temperature protection (OTP) circuit disables the N-channel MOSFET. It indicates a fault condition by setting the FAULT pin LOW. Any transition on the EN pin has no effect. Once the device temperature decreases to below 115 °C, the device returns to the defined state. The OTP circuit is disabled in low-power mode. However, if the OTP circuit is active, setting the EN pin LOW does not return the device to low-power mode.

8.7 Reverse bias current/back drive protection

When EN is set HIGH, if (VINT + 30 mV) < VBUS < (VINT + 0.45 V) for longer than 4 ms, or if VBUS > (VINT + 0.45 V), the reverse-bias current protection circuit (RCP) disables the N-channel MOSFET. It indicates a fault condition by setting the FAULT pin LOW. Once VBUS < VINT for longer than 4 ms the device returns to the defined state. If the RCP circuit is active, setting the EN pin LOW returns the device to low-power mode.

8.8 FAULT output

The FAULT output is an open-drain output that requires an external pull-up resistor. If any of the UVLO, OVLO, RCP, OCP or OTP circuits are activated the FAULT output is set LOW to indicate a fault has occurred. The FAULT output returns to the high impedance state automatically once the fault condition is removed.

8.9 **VDET output**

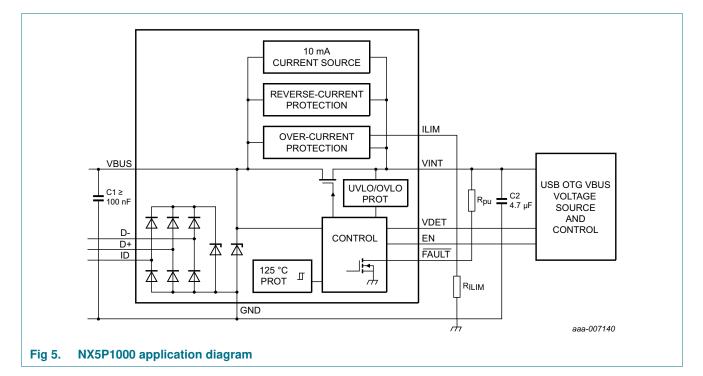
VDET is an analog output that allows a controller to monitor the voltage level on VBUS.

8.10 In-rush current protection

When either the EN pin or a recovered fault condition enables the N-channel MOSFET, the in-rush current protection circuit affects the switch. It causes the switch to behave as a current source during the time VBUS ramps up to VINT - 200 mV. The resistor connected to ILIM determines the current. The in-rush current protection circuit is disabled in low-power mode.

9. Application diagram

The NX5P1000 typically connects a voltage source on VINT to the VBUS of a USB connector supporting USB3 OTG in a portable, battery operated device. The external resistor R_{ILIM} sets the maximum current limit threshold. The FAULT signal requires an additional external pull-up resistor. This resistor should be connected to a supply voltage matching the logic input pin supply level it is connected to.



10. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|---------------------------------|-----------------------------|-----------------|------------|------|
| VI | input voltage | VBUS | <u>[1]</u> –0.5 | +32 | V |
| | | VINT | <u>[1]</u> –0.5 | +6.0 | V |
| | | EN, ILIM | <u>[2]</u> –0.5 | VINT + 0.5 | V |
| | | D-, D+, ID | <u>[1]</u> –0.5 | +6.0 | V |
| Vo | output voltage | FAULT | -0.5 | +6.0 | V |
| I _{IK} | input clamping current | EN: V _I < -0.5 V | -50 | - | mA |
| I _{SK} | switch clamping current | VBUS; VINT; $V_I < -0.5 V$ | -50 | - | mA |
| I _{SW} | switch current | T _{amb} = 85 °C | - | ±1000 | mA |
| T _{j(max)} | maximum junction temperature | | -40 | +125 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | | [3] _ | 100 | mW |
| | | | | | |

[1] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

[3] The (absolute) maximum power dissipation depends on the junction temperature T_j . Higher power dissipation is allowed in conjunction with lower ambient temperatures. The conditions to determine the specified values are $T_{amb} = 85$ °C and the use of a two layer PCB.

11. Recommended operating conditions

Table 7. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|----------------|-----|------|------|
| VI | input voltage | VINT | 3.0 | 5.5 | V |
| | | EN, ILIM | 0 | VINT | V |
| Vo | output voltage | VBUS; EN = LOW | 0 | 30 | V |
| V _{I/O} | input/output voltage | D-, D+, ID | 0 | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | +85 | °C |
| - | | | | | |

12. Thermal characteristics

Table 8. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------------|---|------------|------------------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | | <u>[1][2]</u> 73 | K/W |

[1] The overall R_{th(j-a)} can vary depending on the board layout. To minimize the effective R_{th(j-a)}, all pins must have a solid connection to larger Cu layer areas e.g. to the power and ground layer. In multi-layer PCB applications, the second layer should be used to create a large heat spreader area right below the device. If this layer is either ground or power, it should be connected with several vias to the top layer connecting to the device ground or supply. Try not to use any solder-stop varnish under the chip.

[2] Rely on the measurement data given for a rough estimation of the R_{th(j-a)} in your application. The actual R_{th(j-a)} value may vary in applications using different layer stacks and layouts

13. Static characteristics

Table 9. Static characteristics

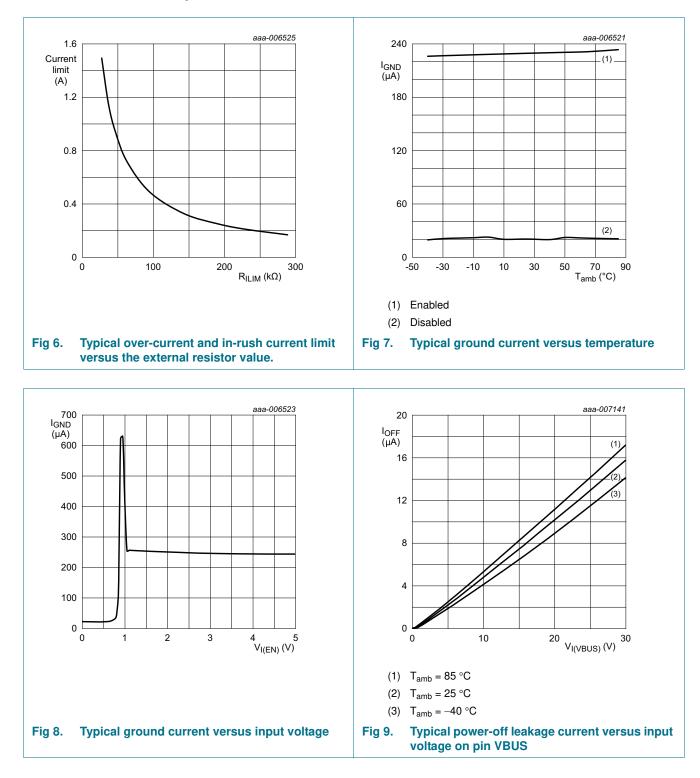
 $V_{I(VINT)} = 4.0 \text{ V}$ to 5.5 V; unless otherwise specified; Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Ta | _{mb} = 25 | °C | $T_{amb} = -40$ ° | C to +85 °C | Contract Contract |
|------------------------|---|--|-----|-----|--------------------|-----------------|-------------------|-----------------|-------------------|
| | | | | Min | Typ[1] | Max | Min | Max | |
| V _{IH} | HIGH-level input voltage | EN input | | 1.2 | - | - | 1.2 | - | V |
| V _{IL} | LOW-level input voltage | EN input | | - | - | 0.4 | - | 0.4 | V |
| Vo | output voltage | VDET; $I_{VDET} = -2 \text{ mA}$; 3 V < VBUS < 30 V | | 1.5 | - | 5.5 | 1.5 | 5.5 | V |
| V _{OL} | LOW-level output voltage | FAULT, I _O = 8 mA | | - | - | 0.5 | - | 0.5 | V |
| Ι _Ο | output current | Current source | | - | 10 | - | 8 | 15 | mA |
| | | EN = HIGH; FAULT = Hi-Z | | - | - | I _{OS} | - | I _{OS} | mA |
| I _{ocp} | overcurrent protection current | EN = HIGH; see Figure 6 | | - | - | - | - | - | mA |
| R _{pu} | pull-up resistance | FAULT | | 20 | - | 200 | - | - | kΩ |
| V _{pu} | pull-up voltage | FAULT | | - | - | VINT | - | VINT | V |
| R _{ILIM} | current limit resistance | ILIM | | 40 | - | 300 | 40 | 300 | kΩ |
| I _{GND} | ground current | VBUS open; EN = LOW; see <u>Figure 7</u> and <u>Figure 8</u> | | - | 20 | - | - | 40 | μA |
| | | VBUS open; EN = HIGH; see <u>Figure 7</u> and <u>Figure 8</u> | | - | 220 | - | - | 330 | μA |
| I _{OFF} | power-off leakage current | VBUS = 0 V to 30 V; VINT = 0 V; see <u>Figure 9</u> | [2] | - | 2 | - | - | 20 | μA |
| $I_{S(OFF)}$ | OFF-state leakage current | VBUS = 0 V to 30 V; see <u>Figure 10</u> and <u>Figure 11</u> | [2] | - | 2 | - | - | 20 | μA |
| V _{UVLO} | undervoltage lockout voltage | | | 3.0 | 3.2 | 3.4 | 3.0 | 3.4 | V |
| V _{OVLO} | overvoltage lockout voltage | | | 5.5 | 5.75 | 6.0 | 5.5 | 6.0 | V |
| V _{hys(OVLO)} | overvoltage lockout hysteresis voltage | | | - | 150 | - | - | - | mV |
| C _{I/O} | input/output capacitance | D-, D+, ID | | - | 3 | - | - | - | pF |
| CI | input capacitance | EN | | - | 2 | - | - | - | pF |
| C _{S(ON)} | ON-state capacitance | | | - | - | 1 | - | 1 | nF |

[1] Typical values are measured at T_{amb} = 25 $^{\circ}C$ and $V_{I(VINT)}$ = 5.0 V.

[2] Typical value is measured at T_{amb} = 25 $^{\circ}C$ and $V_{I(VBUS)}$ = 5.0 V.

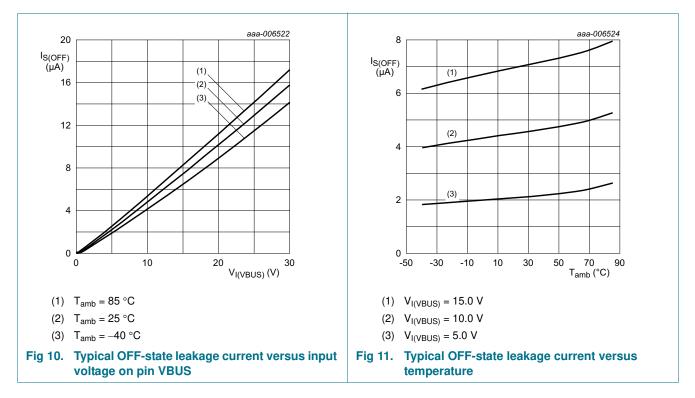
Logic controlled high-side power switch



13.1 Graphs

NX5P1000

Logic controlled high-side power switch



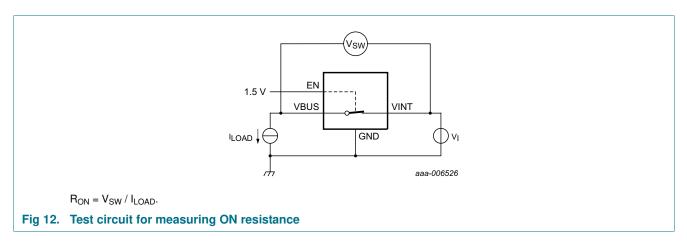
13.2 ON resistance

Table 10.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V)

| Symbol | Parameter | Conditions | Tar | _{mb} = 25 | °C | $T_{amb} = -40$ | °C to +85 °C | Unit |
|-----------------|---------------|--|-----|--------------------|-----|-----------------|--------------|------|
| | | | Min | Тур | Max | Min | Мах | |
| R _{ON} | ON resistance | switch enabled; I _{LOAD} = 200 mA; see <u>Figure 12</u> , <u>Figure 13</u> and <u>Figure 14</u> | | | | | | |
| | | $V_{I(VINT)} = 4.0 V \text{ to } 5.5 V$ | - | 60 | - | - | 100 | mΩ |

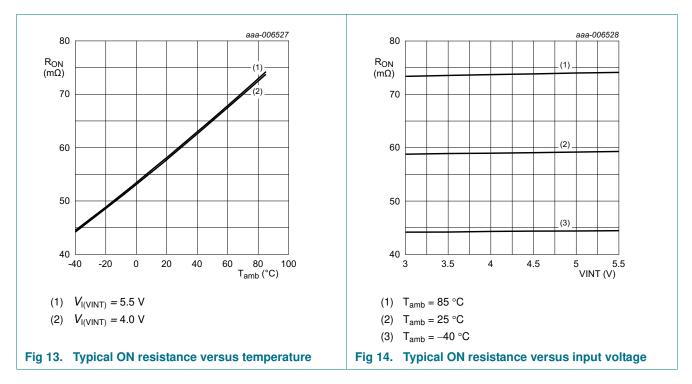
13.3 ON resistance test circuit and waveforms



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NX5P1000

Logic controlled high-side power switch



14. Dynamic characteristics

Table 11. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 16</u>. $V_{I(VINT)} = 4.0 V$ to 5.5 V.

| Symbol | Parameter | Conditions | T _{amb} = 25 °C | | T _{amb} = -40 °C to +85 °C | | Unit | |
|------------------|--|---------------------------|--------------------------|------|-------------------------------------|------|------|----|
| | | | Min | Тур | Max | Min | Max | |
| t _{en} | enable time | EN to VBUS; see Figure 15 | - | 0.24 | - | 0.16 | - | ms |
| t _{dis} | disable time | EN to VBUS; see Figure 15 | - | 1.5 | - | - | - | ms |
| t _{on} | turn-on time | EN to VBUS; see Figure 15 | - | 0.63 | - | 0.52 | - | ms |
| t _{off} | turn-off time | EN to VBUS; see Figure 15 | - | 34.5 | - | - | - | ms |
| t _{TLH} | LOW to HIGH output transition time | VBUS; see Figure 15 | - | 0.39 | - | 0.16 | - | ms |
| t _{THL} | HIGH to LOW output transition time | VBUS; see Figure 15 | - | 33 | - | - | - | ms |

Logic controlled high-side power switch

14.1 Waveforms, graphs and test circuit

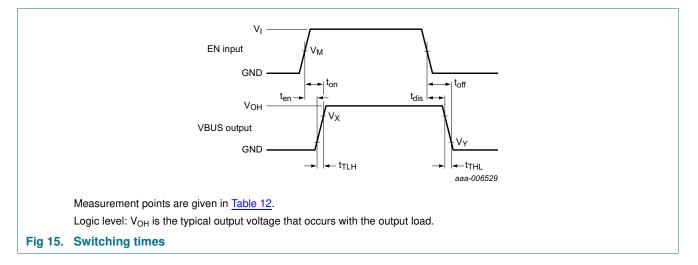


Table 12. Measurement points

| Supply voltage | EN Input | Output | |
|----------------------|-------------------|--------------------|---------------------|
| V _{I(VINT)} | V _M | V _X | V _Y |
| 4.0 V to 5.5 V | $0.5 	imes V_{I}$ | $0.9 	imes V_{OH}$ | $0.1 \times V_{OH}$ |

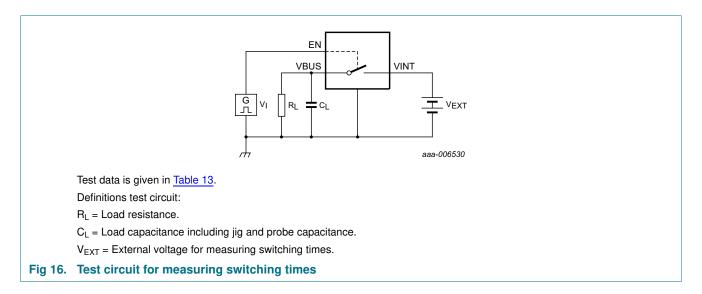


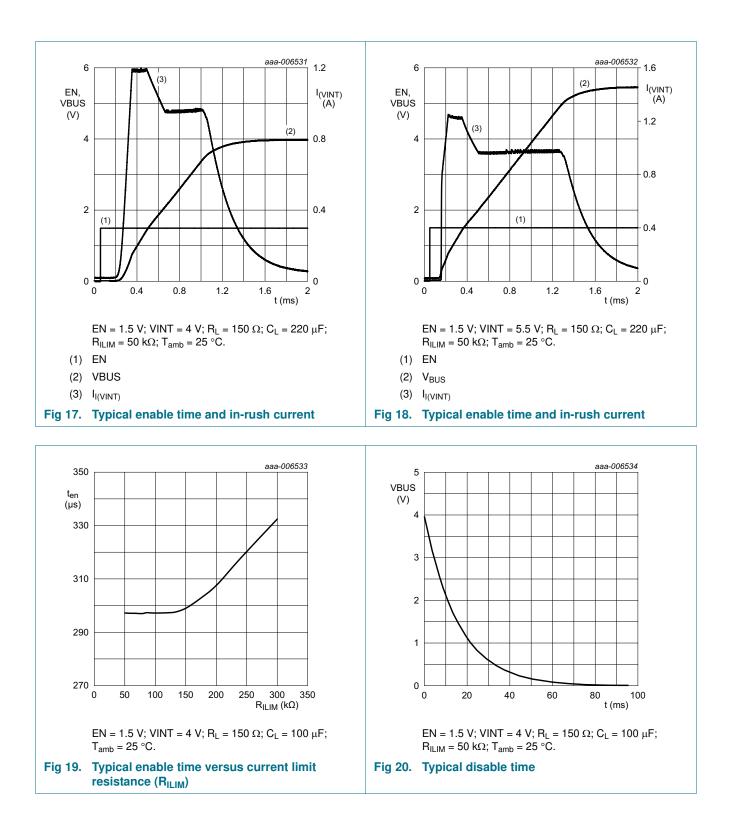
Table 13. Test data

| Supply voltage | Input | Load | |
|------------------|-------|--------|-------|
| V _{EXT} | Vi | CL | RL |
| 4.0 V to 5.5 V | 1.5 V | 100 μF | 150 Ω |

NX5P1000 Product data sheet

NX5P1000

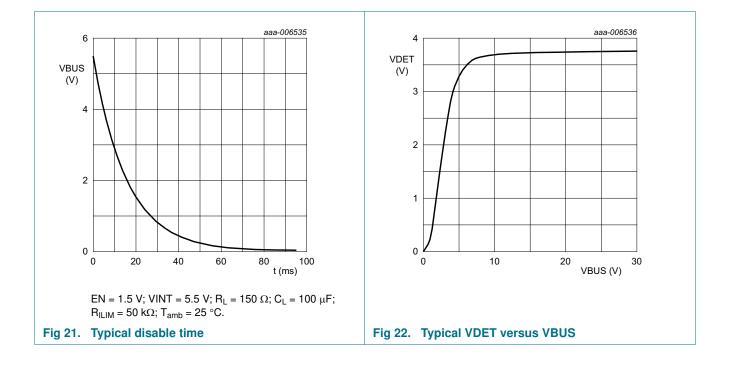
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NX5P1000

Logic controlled high-side power switch



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Logic controlled high-side power switch

15. Package outline

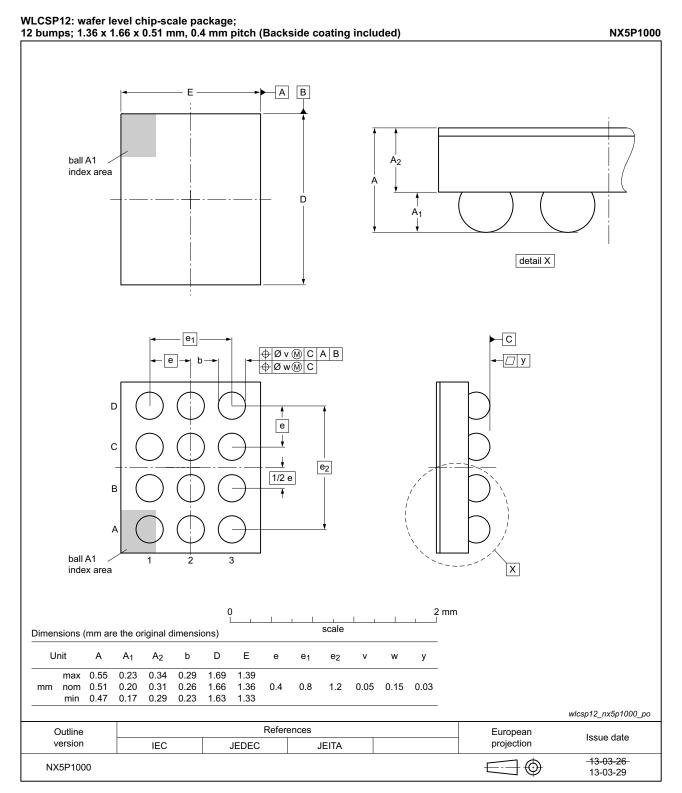


Fig 23. Package outline NX5P1000 (WLCSP12)

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16. Abbreviations

| Table 14. | Abbreviations |
|-----------|---|
| Acronym | Description |
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MOSFET | Metal-Oxide Semiconductor Field Effect Transistor |
| OCP | Overcurrent Protection |
| OTP | Overtemperature Protection |
| RCP | Reverse Current Protection |
| USB OTG | Universal Serial Bus On-The-Go |
| UVLO | Undervoltage lockout |
| VBUS | USB Power Supply |
| OVLO | Overvoltage lockout |

17. Revision history

Table 15.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|---------------------------------|---------------|--------------|
| NX5P1000 v.2 | 20140114 | Product data sheet | - | NX5P1000 v.1 |
| Modifications: | I_{OS} changed | into I _{ocp} (errata). | | |
| NX5P1000 v.1 | 20130429 | Product data sheet | - | - |

18. Legal information

18.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Logic controlled high-side power switch

20. Contents

| 1 | General description | . 1 |
|-------------|--|-----|
| 2 | Features and benefits | . 1 |
| 3 | Applications | |
| 4 | Ordering information | |
| 5 | Marking | |
| 6 | Functional diagram | |
| 7 | Pinning information | |
| 7.1 | Pinning | |
| 7.2 | Pin description | |
| 8 | Functional description | |
| 8.1 | EN input. | |
| 8.2 | Undervoltage lockout | |
| 8.3 | Overvoltage lockout | |
| 8.4 | ILIM | |
| 8.5 | Over-current protection | |
| 8.6 | Over-temperature protection | |
| 8.7 | Reverse bias current/back drive protection | |
| 8.8 | FAULT output | |
| 8.9 8.10 | VDET output | |
| | | |
| 9 | Application diagram | |
| 10 | Limiting values. | |
| 11 | Recommended operating conditions | |
| 12 | Thermal characteristics | |
| 13 | Static characteristics | |
| 13.1 | Graphs | |
| 13.2 | ON resistance | |
| 13.3 | ON resistance test circuit and waveforms | 10 |
| 14 | Dynamic characteristics | 11 |
| 14.1 | Waveforms, graphs and test circuit | 12 |
| 15 | Package outline | 15 |
| 16 | Abbreviations | 16 |
| 17 | Revision history | 16 |
| 18 | Legal information | 17 |
| 18.1 | Data sheet status | 17 |
| 18.2 | Definitions | 17 |
| 18.3 | Disclaimers | 17 |
| 18.4 | Trademarks | 18 |
| 19 | Contact information | 18 |
| | Contents | |

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